NSN 5962-01-316-3521

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-316-3521 **Body Length:** Between 0.442 inches and 0.460 inches **Body Width:** Between 0.442 inches and 0.460 inches **Body Height:** Between 0.060 inches and 0.100 inches **Maximum Power Dissipation Rating:** 1.018 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Programmable and monolithic and 3-state output and bipolar and w/clock **Inclosure Material:** Ceramic **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 18 input **Case Outline Source And Designator:** C-4 mil-m-38510 **Current Rating Per Characteristic:** 185.00 milliamperes forward current, nonrepetitive, peak total value absolute **Terminal Surface Treatment:** Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Memory Device Type:

Programmable

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 leadless

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

NSN 5962-01-316-3521

Memory Microcircuit - Page 2 of 2



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